

Rectifier – STEALTH™ II

8 A, 600 V

FFD08S60S-F085

The FFD08S60S-F085 is stealth 2 rectifier with soft recovery characteristics ($t_{rr} < 30$ ns). They has half the recovery time of hyperfast rectifier and are silicon nitride passivated ion-implanted epitaxial planar construction. This device is intended for use as freewheeling of boost diode in switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Features

- High Speed Switching (Max. $t_{rr} < 30$ ns @ $I_F = 8$ A)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- Pb-Free and RoHS Compliant

Applications

- General Purpose
- Switching Mode Power Supply
- Boost Diode in Continuous Mode Power Factor Corrections
- Power Switching Circuits

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Ratings | Unit |
|----------------|--|--------------|------------------|
| V_{RRM} | Peak Repetitive Reverse Voltage | 600 | V |
| V_{RWM} | Working Peak Reverse Voltage | 600 | V |
| V_R | DC Blocking Voltage | 600 | V |
| $I_{F(AV)}$ | Average Rectified Forward Current @ $T_C = 115^\circ\text{C}$ | 8 | A |
| I_{FSM} | Non-repetitive Peak Surge Current 60 Hz Single Half-Sine Wave | 80 | A |
| T_J, T_{STG} | Operating Junction and Storage Temperature | -65 to + 150 | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

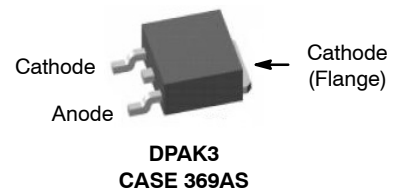
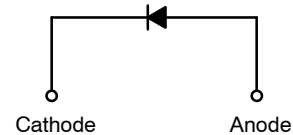
THERMAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Ratings | Unit |
|-----------------|---|---------|---------------------------|
| $R_{\theta JC}$ | Maximum Thermal Resistance, Junction to Case | 3.0 | $^\circ\text{C}/\text{W}$ |

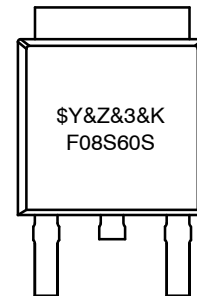


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MARKING DIAGRAM



\$Y = ON Semiconductor Logo
 &Z = Assembly Plant Code
 &3 = Numeric Date Code
 &K = Lot Code
 F08S60S = Specific Device Code

ORDERING INFORMATION

| Device | Package | Shipping |
|---------------|--------------------|-----------------------|
| FFD08S60-F085 | DPAK3 (Pb-Free) | 2500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|----------------------|--|---|--|---------------------------|------------|---------------|
| V_{FM} (Note 1) | $I_F = 8\text{ A}$, $I_R = 8\text{ A}$ | $T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$ | - | 2.1 1.6 | 2.6 - | V |
| I_{RM} (Note 1) | $V_R = 600\text{ V}$, $V_R = 600\text{ V}$ | $T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$ | - | - | 100 500 | μA |
| t_{rr} | $I_F = 1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$ | $T_C = 25^\circ\text{C}$ | - | - | 25 | ns |
| t_{rr} | $I_F = 8\text{ A}$, $di/dt = 200\text{ A}/\mu\text{s}$, $V_R = 390\text{ V}$ | $T_C = 25^\circ\text{C}$ | - | 19 | 30 | ns |
| I_{rr} | | | - | 2.2 | - | A |
| S factor | | | - | 0.6 | - | |
| Q_{rr} | | | - | 21 | - | nC |
| t_{rr} | | | $I_F = 8\text{ A}$, $di/dt = 200\text{ A}/\mu\text{s}$, $V_R = 390\text{ V}$ | $T_C = 125^\circ\text{C}$ | - | 58 |
| I_{rr} | - | 4.3 | | | - | A |
| S factor | - | 1.3 | | | - | |
| Q_{rr} | - | 125 | | | - | nC |
| W_{AVL} | Avalanche Energy ($L = 40\text{ mH}$) | | 20 | - | - | mJ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse width = 300 μs , Duty Cycle = 2%.

TEST CIRCUIT AND WAVEFORMS

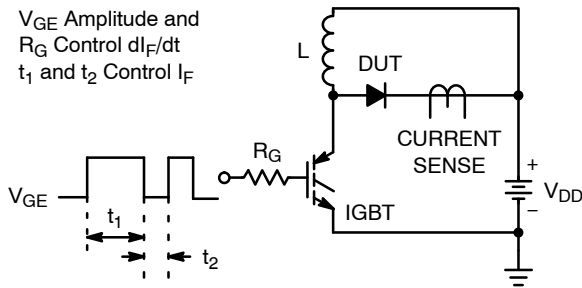


Figure 1. t_{rr} Test Circuit

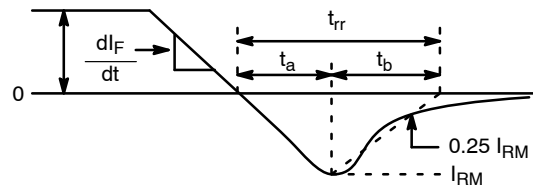


Figure 2. t_{rr} Waveform and Definitions

$I_{MAX} = 1\text{ A}$
 $L = 40\text{ mH}$
 $R < 0.1\ \Omega$
 $V_{DD} = 50\text{ V}$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$
 $Q_1 = \text{IGBT } (BV_{CES} > \text{DUT } V_{R(AVL)})$

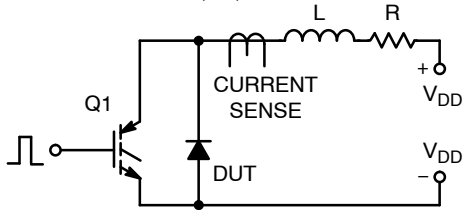


Figure 3. Avalanche Energy Test Circuit

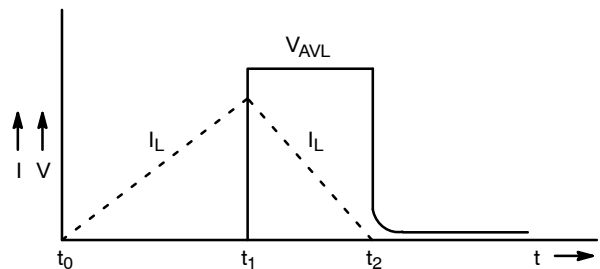


Figure 4. Avalanche Current and Voltage Waveforms

TYPICAL CHARACTERISTICS

($T_C = 25^\circ\text{C}$ unless otherwise noted)

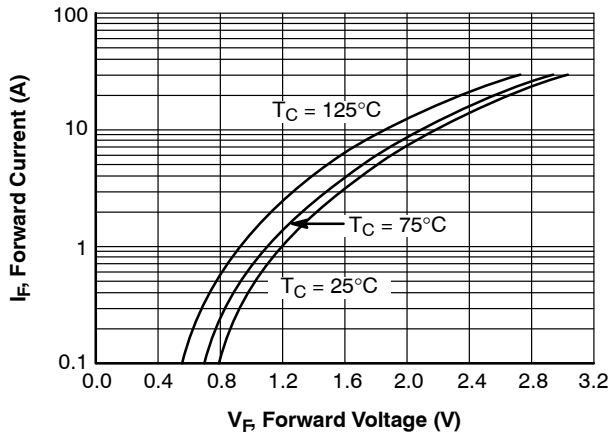


Figure 5. Typical Forward Voltage Drop

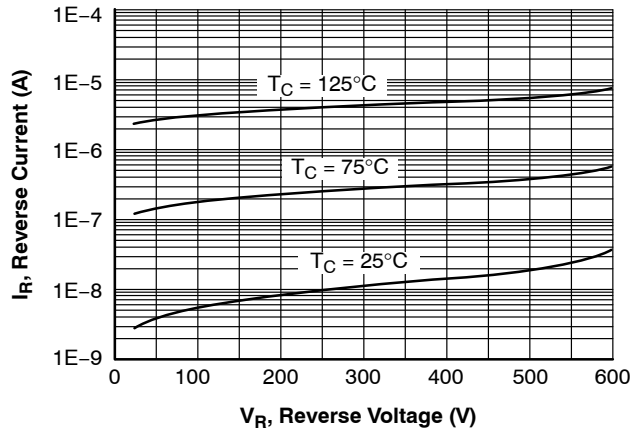


Figure 6. Typical Reverse Current

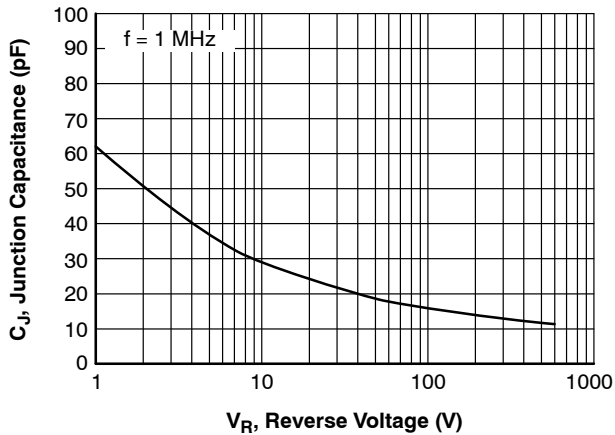


Figure 7. Typical Junction Capacitance

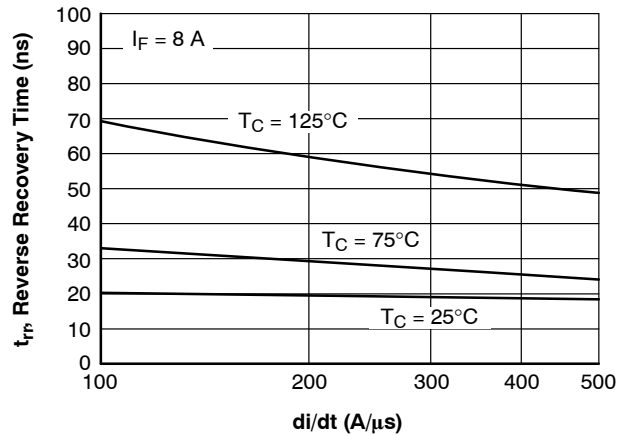


Figure 8. Typical Reverse Recovery Time

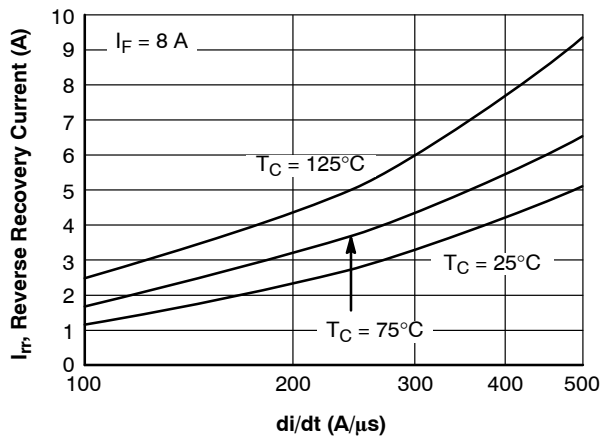


Figure 9. Typical Reverse Recovery Current

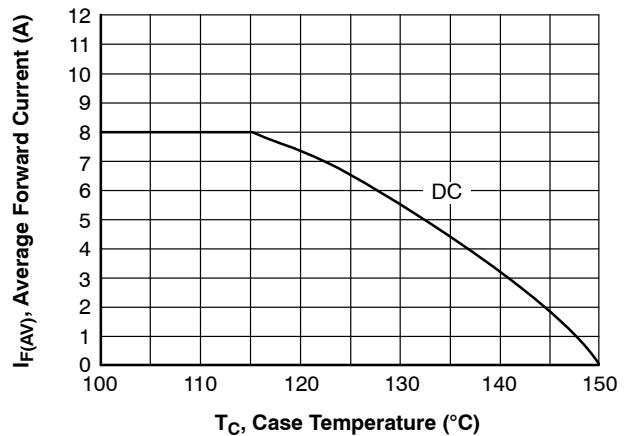
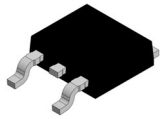


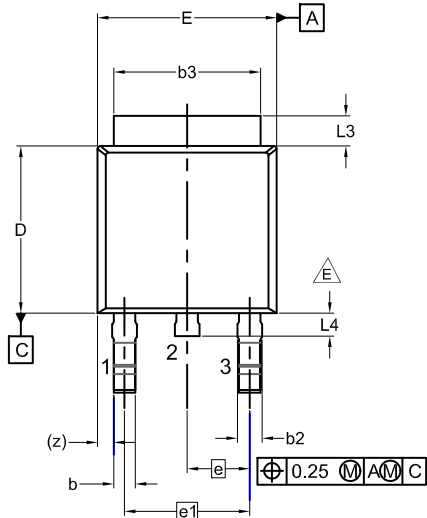
Figure 10. Forward Current Deration Curve

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

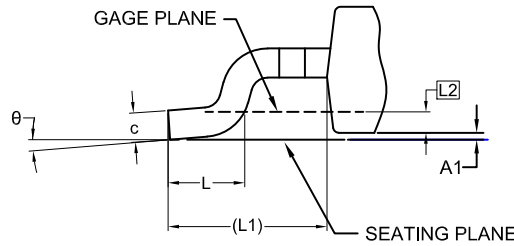


DPAK3 (TO-252 3 LD) CASE 369AS ISSUE A

DATE 28 SEP 2022

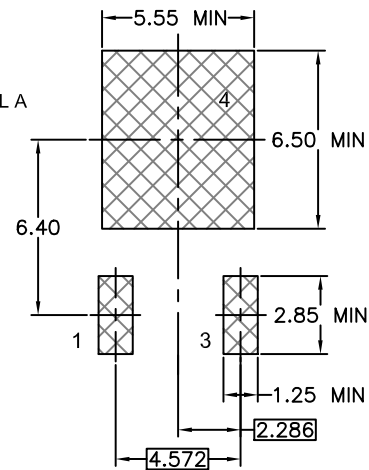
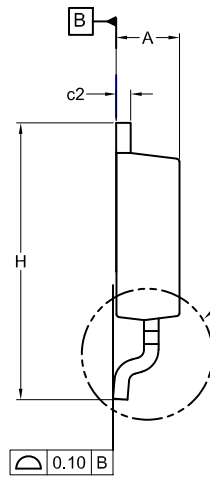
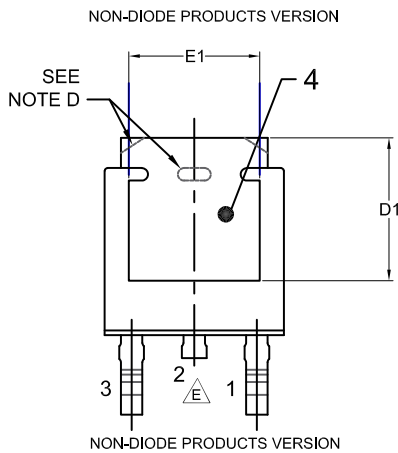


- NOTES: UNLESS OTHERWISE SPECIFIED
 A) THIS PACKAGE CONFORMS TO JEDEC, TO-252, ISSUE C, VARIATION AA.
 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2009.
 D) SUPPLIER DEPENDENT MOLD LOCKING HOLES OR CHAMFERED CORNERS OR EDGE PROTRUSION.
 E) FOR DIODE PRODUCTS, L4 IS 0.25 MM MAX.
 F) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
 G) LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A STD TO228P991X239-3N.



DETAIL A
(ROTATED -90°)
SCALE: 12X

| DIM | MILLIMETERS | | |
|-----|-------------|------|-------|
| | MIN. | NOM. | MAX. |
| A | 2.18 | 2.29 | 2.39 |
| A1 | 0.00 | - | 0.127 |
| b | 0.64 | 0.77 | 0.89 |
| b2 | 0.76 | 0.95 | 1.14 |
| b3 | 5.21 | 5.34 | 5.46 |
| c | 0.45 | 0.53 | 0.61 |
| c2 | 0.45 | 0.52 | 0.58 |
| D | 5.97 | 6.10 | 6.22 |
| D1 | 5.21 | - | - |
| E | 6.35 | 6.54 | 6.73 |
| E1 | 4.32 | - | - |
| e | 2.286 BSC | | |
| e1 | 4.572 BSC | | |
| H | 9.40 | 9.91 | 10.41 |
| L | 1.40 | 1.59 | 1.78 |
| L1 | 2.90 REF | | |
| L2 | 0.51 BSC | | |
| L3 | 0.89 | 1.08 | 1.27 |
| L4 | - | - | 1.02 |
| θ | 0° | -- | 10° |



GENERIC MARKING DIAGRAM*



- XXXX = Specific Device Code
- A = Assembly Location
- Y = Year
- WW = Work Week
- ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

LAND PATTERN RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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